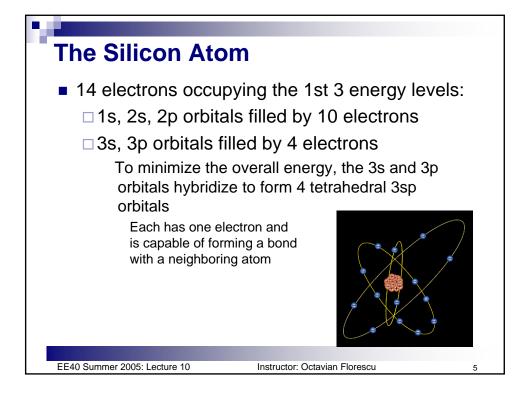
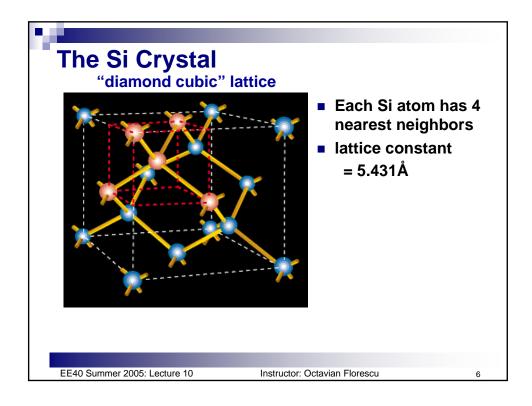
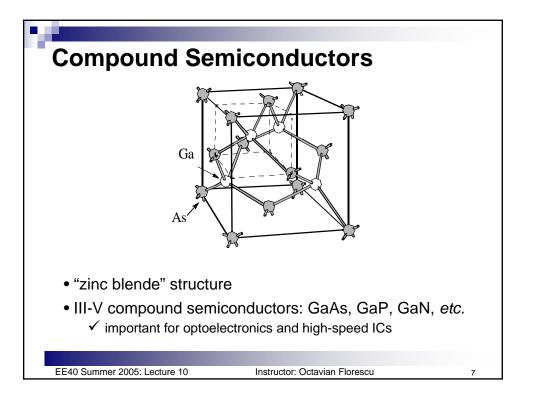
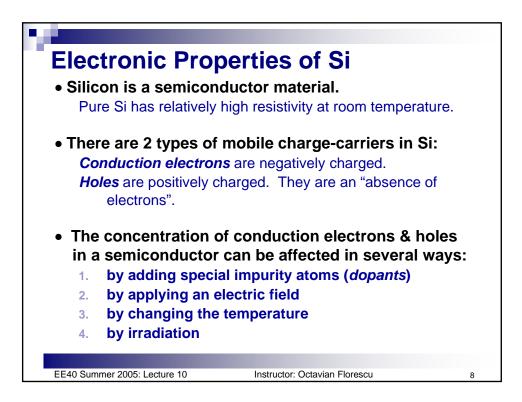


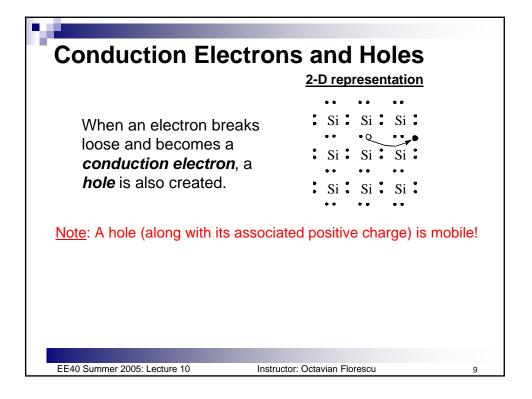
Semiconductor Materials								
		12	13	14	15	16	17	18
<u>Elemental</u> : <u>Compound</u> :		30 Zn	5 B 13 Al 31 Ga	6 C 14 Si 32 Ge	7 N 15 P 33 As	8 0 16 S 34 Se	9 F 17 Cl 35 Br	2 He 10 Ne 18 Ar 36 Kr
		48 Cd 80 Hg 112 J Uub	49 In 81 Tl	50 Sn 82 Pb 114 Uuq	51 Sb 83 Bi	52 Te 84 Po 116 Uuh	53 I 85 At	54 Xe 86 Rn 118 Uuo
		66 Dy 98 Cf	67 Ho 99 Es	68 Er 100 Fm	69 Tm 101 Md	70 Yb 102 No		
EE40 Summer 2005: Lecture 10	Instructor: Octavian Florescu							4

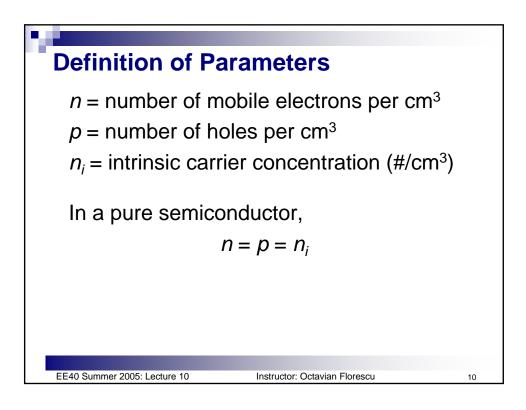


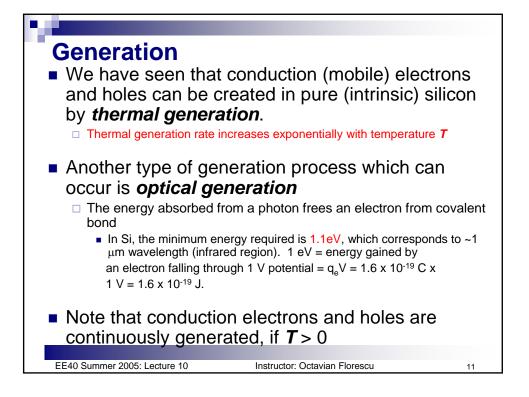


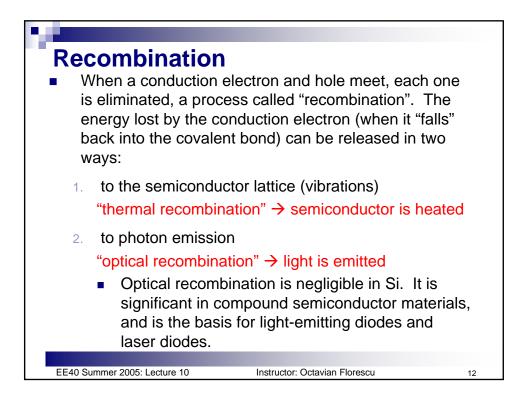


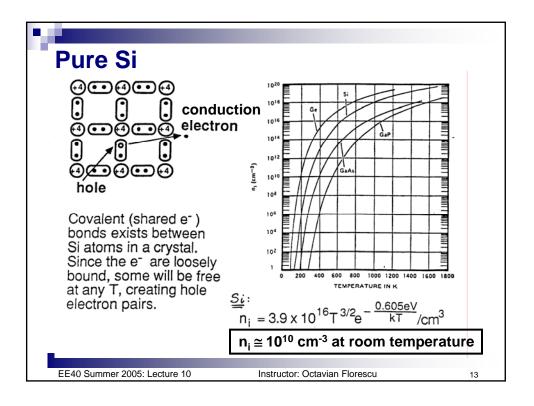


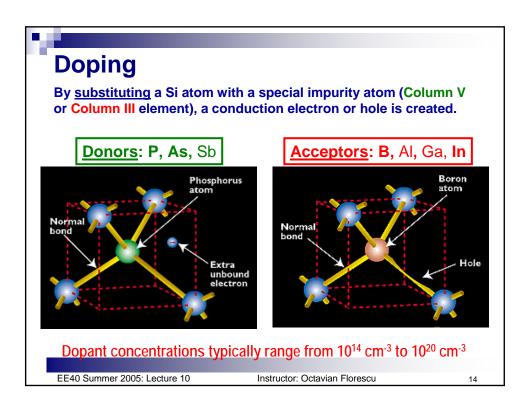


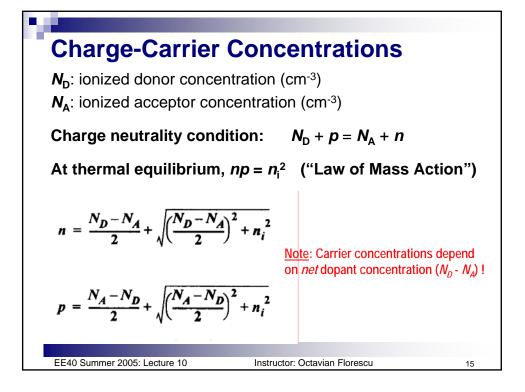












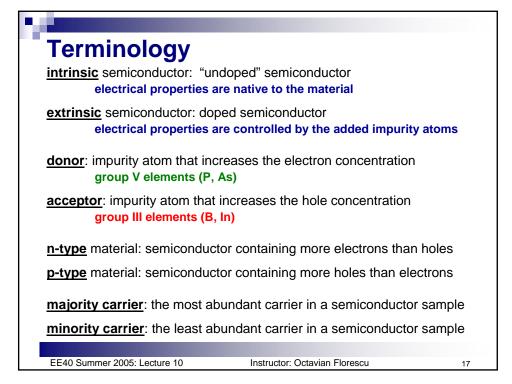
N-type and P-type Material

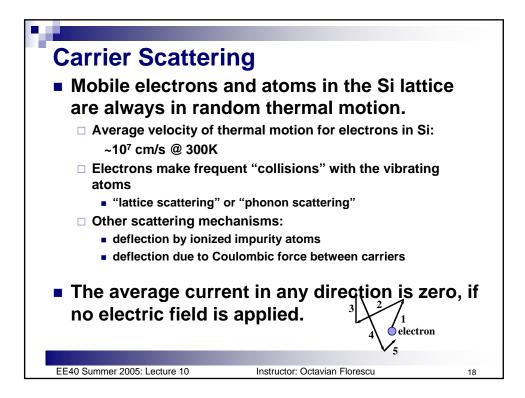
 If
$$N_D >> N_A$$
 (so that $N_D - N_A >> n_i$):

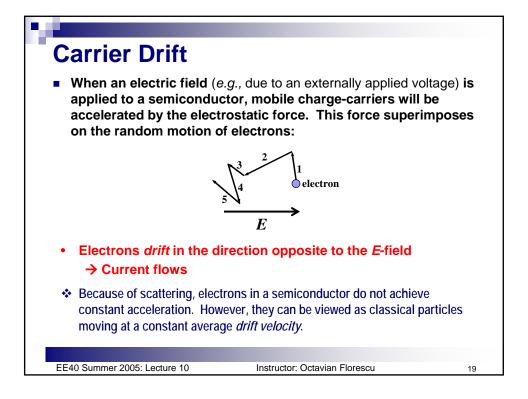
 $n \cong N_D - N_A$ and $p \cong \frac{n_i^2}{N_D - N_A}$
 $n >> p \rightarrow$ material is "n-type"

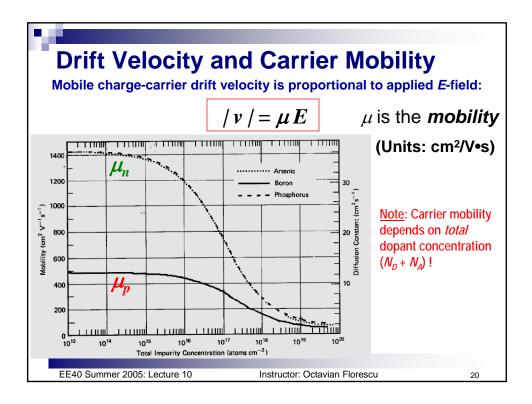
 If $N_A >> N_D$ (so that $N_A - N_D >> n_i$):

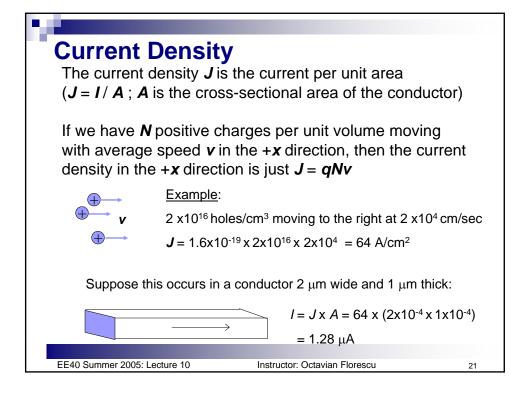
 $p \cong N_A - N_D$ and $n \cong \frac{n_i^2}{N_A - N_D}$
 $p >> n \rightarrow$ material is "p-type"

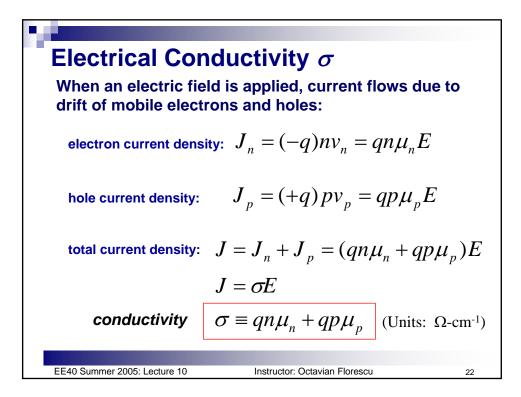


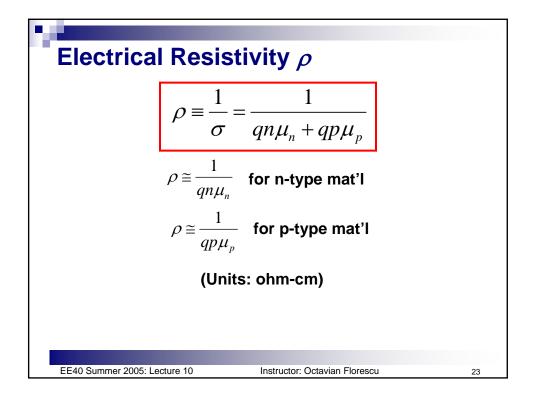


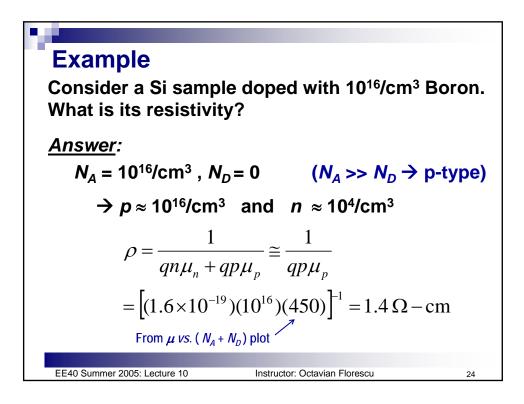












Example (cont'd)

Consider the same Si sample, doped *additionally* with 10¹⁷/cm³ Arsenic. What is its resistivity?

Answer:

$$N_{A} = 10^{16}/\text{cm}^{3}, N_{D} = 10^{17}/\text{cm}^{3} (N_{D} \gg N_{A} \Rightarrow \text{n-type})$$

$$\Rightarrow n \approx 9 \times 10^{16}/\text{cm}^{3} \text{ and } p \approx 1.1 \times 10^{3}/\text{cm}^{3}$$

$$\rho = \frac{1}{qn\mu_{n} + qp\mu_{p}} \cong \frac{1}{qn\mu_{n}}$$

$$= \left[(1.6 \times 10^{-19})(9 \times 10^{16})(700) \right]^{-1} = 0.10 \,\Omega - \text{cm}$$

The sample is converted to n-type material by adding more donors than acceptors, and is said to be "compensated".

